



Form PTO-1449		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE			ATTY. DOCKET NO. 30-5000-(4015)-Div3		SERIAL NO. 09/783,835	
LIST OF ART CITED BY APPLICANT (Use several sheets if necessary)					APPLICANT Shozo Nagano et al.			# 18
					FILING DATE February 14, 2001		GROUP 1742	
U.S. PATENT DOCUMENTS								
*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate	
B	AA	5,312,790	05-1994	Sengupta et al.	522	127		
B	AB	5,435,826	07-1995	Sakakibara et al.	75	232		
B	AC	5,486,491	01-1996	Sengupta	501	137		
B	AD	6,451,135 B1	09-2002	Takahashi	148	432		
B	AE	6,478,902 B2	11-2002	Koenigsmann et al.	148	681		
	AF							
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	AK							
FOREIGN PATENT DOCUMENTS								
		Document Number	Date	Country	Class	Subclass	Translation	
							Yes	No
B	AL	11323539	11-1999	Japan				
B	AM	0441408A2	08-1991	EPO				
	AN							
	AO							
	AP							
OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, Etc.)								
B	AR		Yeon et al., "Electrical Characteristics of the MOD-derived SrBi ₂ xTa ₂ O ₉ and SrBi _{2.4} (TA,Nb) ₂ O ₉ Thin Films", Journal of Materials Science, 35(10), pgs. 2405-2411, May 15, 2000. Abstract only.					
B	AS		Yan et al., "Preparation on the [(Pb,Ln) (Zr,Ti)O ₃] Ferroelectric Thin Films by Using the Sol-Gel Processing", Piezoelectrics and Acoustooptics, Volume 17, issue n 5, October 1995, pgs. 24-27.					
	AT							
EXAMINER			DATE CONSIDERED					
S I P			5/19/03					
<small>*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.</small>								

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